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30V P-Channel PowerTrench[®] MOSFET

General Description

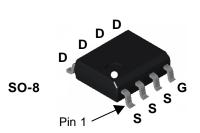
This PChannel MOSFET is a rugged gate version of Fairchild Semiconductor's advanced PowerTrench process. It has been optimized for power management applications requiring a wide range of gave drive voltage ratings (4.5V - 25V).

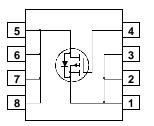
Applications

- Power management
- · Load switch
- Battery protection

Features

- -8.8 A, -30 V $R_{\text{DS(ON)}} = 20 \text{ m}\Omega @ \text{V}_{\text{GS}} = -10 \text{ V}$ $R_{\text{DS(ON)}} = 35 \text{ m}\Omega @ \text{V}_{\text{GS}} = -4.5 \text{ V}$
- Low gate charge (17nC typical)
- · Fast switching speed
- + High performance trench technology for extremely low $R_{\text{DS}(\text{ON})}$
- High power and current handling capability





Absolute Maximum Ratings T_A=25°C unless otherwise noted

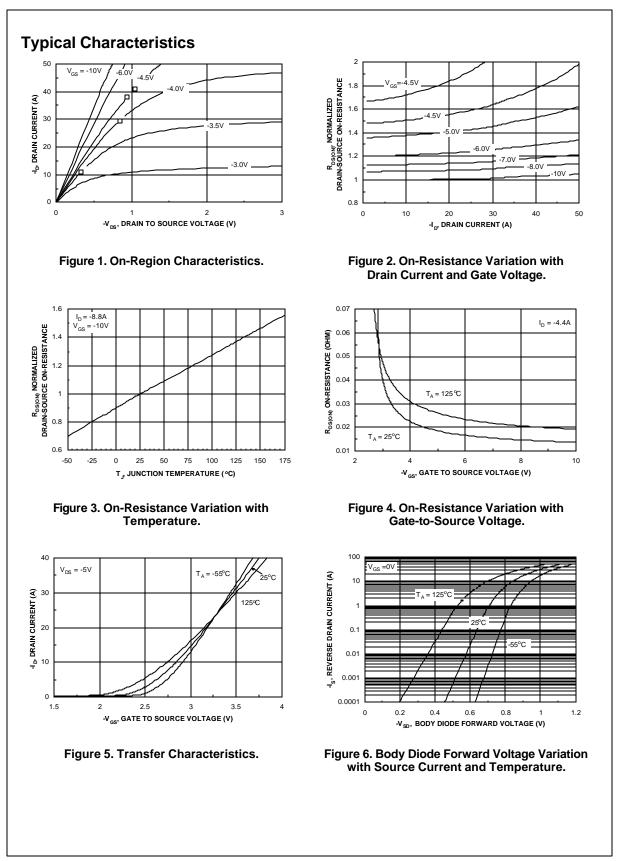
Symbol		Parameter	Ratings	Units	
V _{DSS}	Drain-Sour	ce Voltage		-30	V
V _{GSS}	Gate-Source	e Voltage		±25	V
D	Drain Current – Continuous		(Note 1a)	-8.8	А
	– Pulsed			-50	
PD	Power Dissipation for Single Operation			2.5	W
			(Note 1b)	1.2	
			(Note 1c)	1	
T _J , T _{STG}	Operating a	and Storage Junction T	-55 to +175	°C	
Therma R _{0JA}	I Charac	teristics esistance, Junction-to-A	Ambient (Note 1a)	50	°C/W
R _{0JA}	Thermal Resistance, Junction-to-Ambient (Note 10			125	°C/W
R _{0JC}	Thermal Resistance, Junction-to-Case			25	°C/W
Packag	e Markin	g and Ordering	g Informatio	n	
Device Marking		Device	Reel Size	Tape width	Quantity
FDS4435		FDS4435	13"	12mm	2500 units

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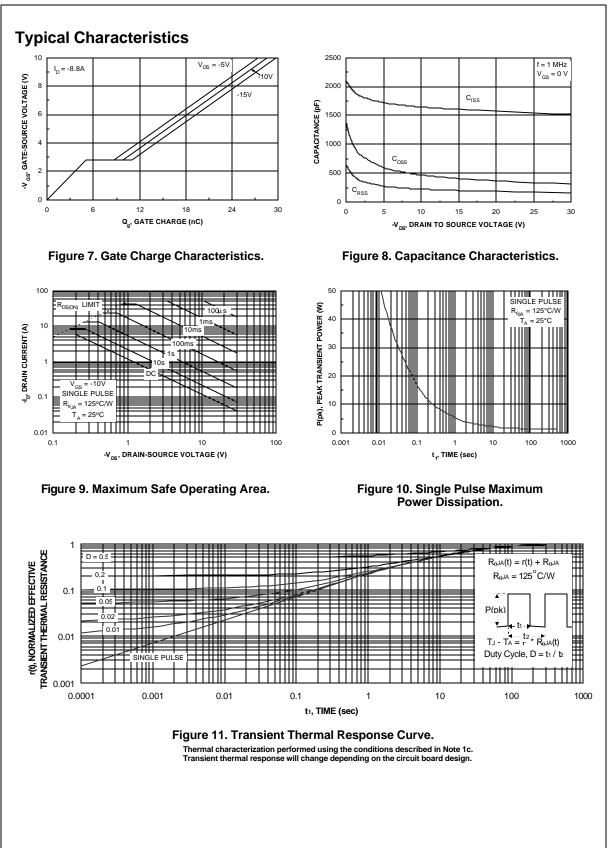
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
- Off Char	acteristics					
BV _{DSS}	Drain–Source Breakdown Voltage	$V_{GS} = 0 V, I_D = -250 \mu A$	-30			V
	Breakdown Voltage Temperature		00			-
ΔT_J	Coefficient	$I_D = -250 \ \mu$ A, Referenced to 25°C		-21		mV/ºC
DSS	Zero Gate Voltage Drain Current	$V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}$			-1	μA
GSSF	Gate–Body Leakage, Forward	$V_{GS} = 25 \text{ V}, \qquad V_{DS} = 0 \text{ V}$			100	nA
GSSR	Gate–Body Leakage, Reverse	$V_{GS} = -25 \text{ V}, V_{DS} = 0 \text{ V}$			-100	nA
On Char	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = -250 \mu A$	-1	-1.7	-3	V
$\Delta V_{GS(th)} \Delta T_J$	Gate Threshold Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$, Referenced to 25°C		5		mV/°C
R _{DS(on)}	Static Drain–Source	$V_{GS} = -10 \text{ V}, I_D = -8.8 \text{ A}$		15	20	mΩ
	On–Resistance	$V_{GS} = -4.5 \text{ V}, I_D = -6.7 \text{ A}$		22	35	
		V_{GS} = -10 V, I_D = -8.8A, T _J =125°C		19	32	
D(on)	On–State Drain Current	$V_{GS} = -10 \text{ V}, V_{DS} = -5 \text{ V}$	-50			A
9fs	Forward Transconductance	$V_{DS} = -5 V$, $I_{D} = -8.8 A$		24		S
Dynamic	Characteristics					
Ciss	Input Capacitance	$V_{DS} = -15 V$, $V_{GS} = 0 V$,		1604		pF
Coss	Output Capacitance	f = 1.0 MHz		408		pF
Crss	Reverse Transfer Capacitance			202		pF
Switchin	g Characteristics (Note 2)	1				
t _{d(on)}	Turn–On Delay Time	$V_{DD} = -15 V$, $I_D = -1 A$,		13	23	ns
tr	Turn–On Rise Time	$V_{GS} = -10 V$, $R_{GEN} = 6 \Omega$		13.5	24	ns
t _{d(off)}	Turn–Off Delay Time			42	68	ns
d(OII)	Turn-Off Fall Time	-		25	40	ns
Qg	Total Gate Charge	$V_{\rm DS} = -15 \text{ V}, I_{\rm D} = -8.8 \text{ A},$		17	24	nC
Q _{gs}	Gate-Source Charge	$V_{BS} = -15 V$, $U_{B} = -0.0 A$, $V_{GS} = -5 V$		5	24	nC
Q _{gd}	Gate-Drain Charge	4		6		nC
0	Ũ			0		11C
Drain-Se				1		1
s		Diode Forward Current			-2.1	A
V _{SD}	Voltage	$V_{GS} = 0 V$, $I_S = -2.1 A$ (Note 2)		-0.73	-1.2	V
Is V _{SD} otes: R _{64A} is the sum	a) 50°C/W when mounted on a 1ir ² pad of 2 oz copper	Diode Forward Current $V_{GS} = 0 V$, $I_S = -2.1 A$ (Note 2) resistance where the case thermal reference is define	للر (c		ng surface o	f

Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width < 300 $\mu s,$ Duty Cycle < 2.0%



FDS4435 Rev F1(W)



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